APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention

METHOD OF FORMING STRAINED SI/SIGE ON INSULATOR WITH SILICON GERMANIUM BUFFER

Application Type: regular, utility

Attorney Docket Number: FIS920030381US1

Correspondence address:

Customer Number: 32074



Inventors Information:

Inventor 1:

Applicant Authority Type: Inventor

Citizenship: CN

Given Name: Huajie

Family Name: Chen

Residence:

City of Residence: Danbury

State of Residence: CT
Country of Residence: US

Address-1 of Mailing Address: 622 Avalon Lake Road

Address-2 of Mailing Address:

City of Mailing Address: Danbury

State of Mailing Address: CT

Postal Code of Mailing Address: 06810

Country of Mailing Address: US

Phone: Fax:

E-mail:

Inventor 2:

Applicant Authority Type: Inventor

Citizenship: US

Given Name: Stephen

Middle Name: W.

Family Name: Bedell

Residence:	
City of Residence:	Poughkeepsie
State of Residence:	NY
Country of Residence:	US
Address-1 of Mailing Address:	32 Nicole Drive
Address-2 of Mailing Address:	
City of Mailing Address:	Poughkeepsie
State of Mailing Address:	NY
Postal Code of Mailing Address:	12590
Country of Mailing Address:	US
Phone:	
Fax:	
E-mail:	
Publication Information: Suggested Figure for Publication - 4F	
Suggested Classification -	
Suggested Technology Center - Total Number of Drawing Sheets - 6	
Assignee 1:	
Organization Name:	International Business Machines Corporation
Address-1 of Mailing Address:	New Orchard Road
Address-2 of Mailing Address:	
City of Mailing Address:	Armonk
State of Mailing Address:	NY
Postal Code of Mailing Address:	10504
Country of Mailing Address:	US
Phone:	
Fax:	
E-mail:	